

**KK75232N/D**

**EIA-232-D INTERFACE 1 CHIP IC**

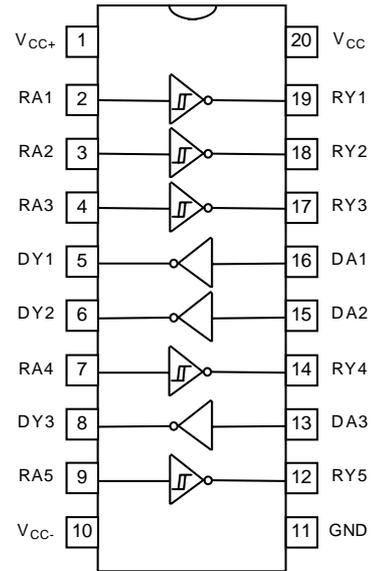
**Description**

The KK75232N, KK75232D are monolithic device containing 3 independent drives and 5 receivers. These are designed to interface between data terminal equipment and data communication equipment as designed by EIA-232-D.

**Features**

- Meets standard EIA-232-D (Revision of RS-232-C)
- Designed to Support Data Rate up to 120kbps
- Drivers
  - Current Limited Output 10 mA Typical
  - Power-off Output Impedance 300 Ω Min
  - Slew Rate Control by Load Capacitor
  - Flexible Supply Voltage Range
  - Input Compatible with Most TTL and DTL Circuits
- Receivers
  - Input Resistance 3 kΩ to 7 kΩ
  - Input Signal Range ± 30 V
  - Built-in Input Hysteresis (Double Threshold)
- 20 DIP/SO20: MS-001AD (KK75232N) / MS-013AC (KK75232D)

**Block Diagram**



KK75232N, KK75232D

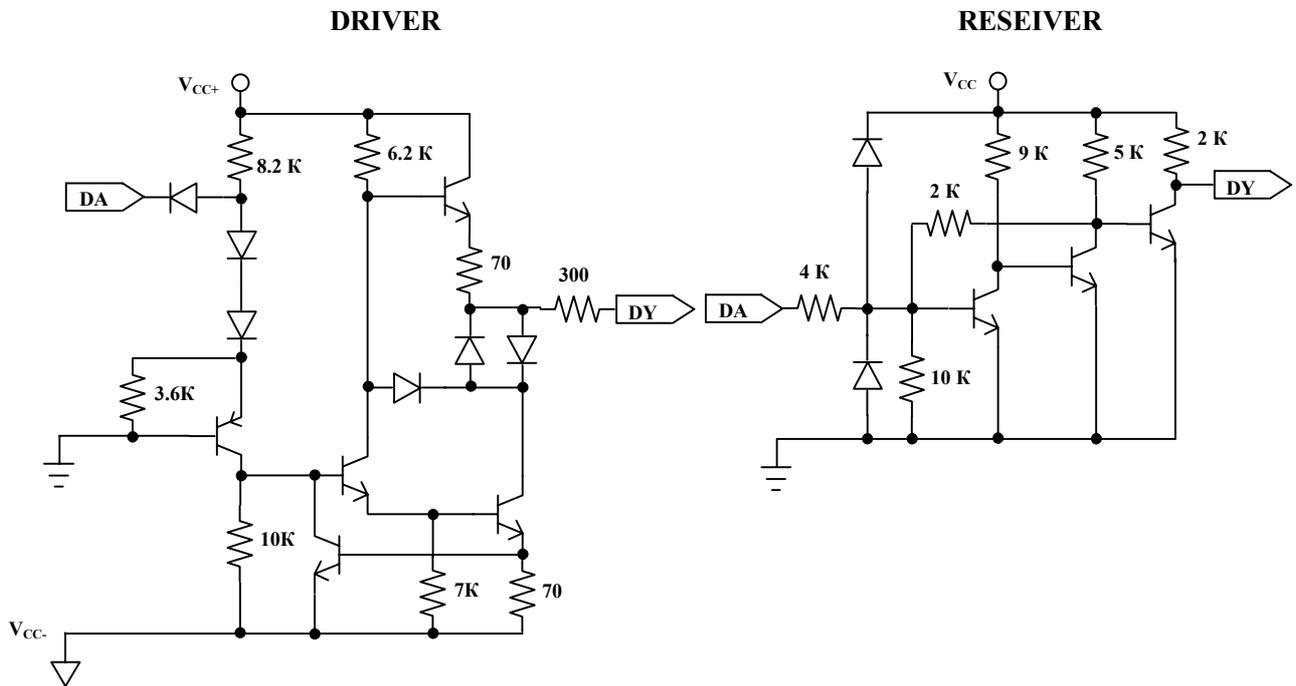
**Pin Description**

Name	Pin No	Function	Name	Pin No	Function
V <sub>CC+</sub>	1	Driver Section Supply +	V <sub>CC-</sub>	10	Driver Section Supply -
DA1	16		DY1	5	
DA2	15		DY2	6	Driver Output
DA3	13	Driver Input	DY3	8	
V <sub>CC</sub>	20	Receiver Section Supply	GND	11	Ground
RA1	2		RY1	19	
RA2	3		RY2	18	
RA3	4	Receiver Input	RY3	17	Receiver Output
RA4	7		RY4	14	
RA5	9		RY5	12	

**Absolute Maximum Ratings**

Symbol	Parameter	Rating	Unit
V <sub>CC+</sub>	Supply Voltage	15	V
V <sub>CC-</sub>	Supply Voltage	-15	V
V <sub>CC</sub>	Supply Voltage	10	V
VI (Driver)	Input Voltage	-15 ÷ +7	V
VI (Reciver)	Input Voltage	± 30	V
VO (Driver)	Output Voltage	-15 ÷ +15	V
PT	Continuous Power Dissipation (Below 25 °C)	1.0	W
T <sub>STG</sub>	Storage Temperature	-65 ÷ +175	°C
Top	Operating Temperature	0 ÷ +75	°C

**Schematic**



## Electrical Characteristics

### Supply Current

 $V_{CC} = 5V, T_A = 25^\circ C$ 

Symbol	Parameter	Test Conditions		Min	Max	Unit
$I_{CC+}$	Supply Current from $V_{CC+}$	$V_{CC+} = 9V$	$V_{IN} = 1.9V$		15	mA
		No Load	$V_{IN} = 0.8V$		4.5	
		$V_{CC+} = 12V$	$V_{IN} = 1.9V$		19	
		No Load	$V_{IN} = 0.8V$		5.5	
		$V_{CC+} = 15V$	$V_{IN} = 1.9V$		25	
		No Load	$V_{IN} = 0.8V$		9	
$I_{CC-}$	Supply Current from $V_{CC-}$	$V_{CC-} = -9V$	$V_{IN} = 1.9V$		-15	mA
		No Load	$V_{IN} = 0.8V$		-3.2	
		$V_{CC-} = -12V$	$V_{IN} = 1.9V$		-19	
		No Load	$V_{IN} = 0.8V$		-3.2	
		$V_{CC-} = -15V$	$V_{IN} = 1.9V$		-25	
		No Load	$V_{IN} = 0.8V$		-3.2	
$I_{CC}$	Supply Current from $V_{CC}$	$V_{CC} = 5V$	$V_{IN} = 5.0V$		30	mA

### Driver Section

Symbol	Parameter	Test Conditions		Min	Max	Unit
$V_{IH}$	High Level	$V_{CC+} = 9V$		1.9		V
	Input Voltage	$V_{CC-} = -9V$				
$V_{IL}$	Low Level				0.8	V
	Input Voltage					
$V_{OH}$	High Level	$V_{IL} = 0.8V$	$V_{CC+} = 9V$	6		V
	Output Voltage	$RL = 3k\Omega$	$V_{CC-} = -9V$			
				$V_{CC+} = 13.2V$	9	
			$V_{CC-} = -13.2V$			
$V_{OL}$	Low Level	$V_{IH} = 1.9V$	$V_{CC+} = 9V$		-6	V
	Output Voltage	$RL = 3k\Omega$	$V_{CC-} = -9V$			
				$V_{CC+} = 13.2V$		-9
			$V_{CC-} = -13.2V$			
$I_{IH}$	High Level	$V_I = 5V$			10	$\mu A$
	Input Current					
$I_{IL}$	Low Level	$V_I = 0$			-1.6	mA
	Input Current					
$I_{OS(H)}$	Short Circuit	$V_I = 0.8V$		-6	-12	mA
	Output Current at High Level	$V_O = 0$				
$I_{OS(L)}$	Short Circuit	$V_I = 1.9V$		6	12	mA
	Output Current at Low Level	$V_O = 0$				
$R_O$	Output Resistance, Power Off	$V_{CC+} = 0, V_{CC-} = 0$ $V_O = -2V$ to $2V$		300		$\Omega$

**Driver Switching Characteristic**
 $V_{CC+} = 9V, V_{CC-} = -9V, T_A = 25\text{ }^{\circ}C$ 

Symbol	Parameter	Test Conditions	Min	Max	Unit
$t_{PLH}$	Propagation Delay Time,	$R_L = 3\text{ k}\Omega$		500	ns
	Low-To-High-Level Output	$C_L = 15\text{ }\mu F$			
$t_{PHL}$	Propagation Delay Time,			175	ns
	High -To- Low -Level Output	See Figure 1			
$t_{TLH}$	Transition Time,			100	ns
	Low-To-High-Level Output *				
$t_{THL}$	Transition Time,			75	ns
	High -To- Low -Level Output*				
$t_{TLH}$	Transition Time,	$R_L = 3\text{ k}\Omega$ to $7\text{ k}\Omega$	2.5		$\mu s$
	Low-To-High-Level Output**	$C_L = 2500\text{ }\rho F$	(tip)		
$t_{THL}$	Transition Time,		3.0		$\mu s$
	High-To-Low -Level Output**	See Figure 1	(tip)		

\*- Measured between 10 % and 90 % Points of Output Waveform

\*\* - Measured between +3V and -3V Points on the Output Waveform (EIA-232-D Condition)

**Receiver Section**

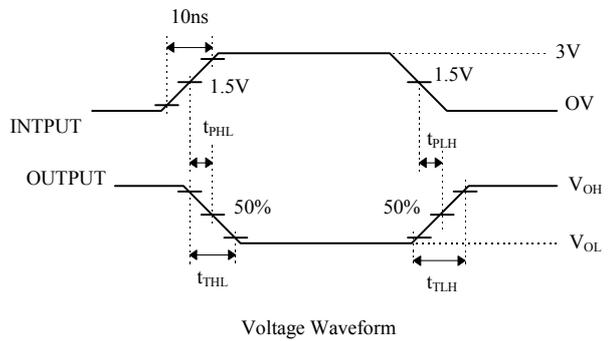
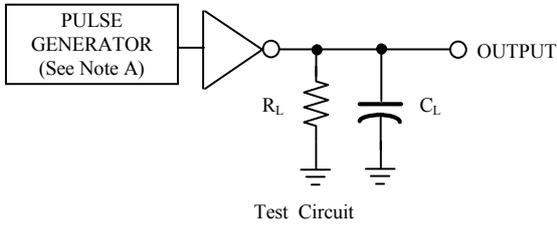
Symbol	Parameter	Test Conditions	Min	Max	Unit
VT+	Positive-Going		1.75	2.25	V
	Threshold Voltage				
VT-	Negative-Going		0.75	1.25	V
	Threshold Voltage				
$V_{OH}$	High Level Output	$V_I = 0.75V, I_{OL} = -0.5mA$	2.6	5	V
	Voltage	Input Open,	2.6	5	
		$I_{OL} = -0.5\text{ mA}$			
$V_{OL}$	Low Level Output Voltage	$V_I = 3V, I_{OL} = 10\text{ mA}$		0.45	V
$I_{IH}$	High-Level Input Current	$V_I = 25V$	3.6	8.3	mA
		$V_I = 3V$	0.43		
$I_{IL}$	Low-Level Input Current	$V_I = -25V$	-3.6	-8.3	mA
		$V_I = -3V$	-0.43		
$I_{OS}$	Short-Circuit		-3		mA
	Output Current		(tip)		

**Receiver Switching Characteristic**
 $V_{CC} = 5V$ 

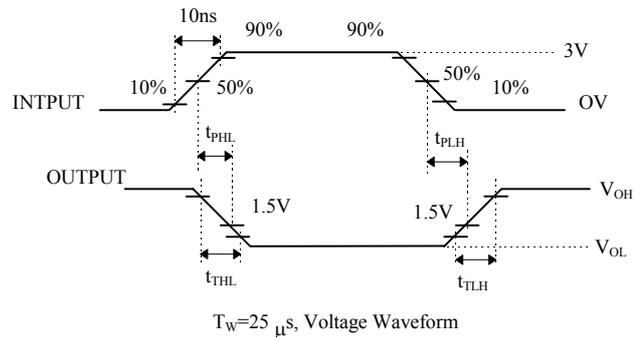
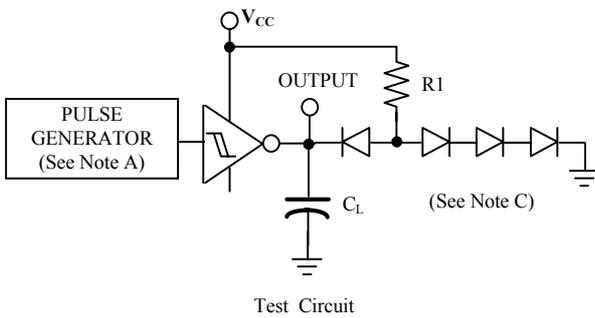
Symbol	Parameter	Test Conditions	Min	Max	Unit
$t_{PLH}$	Propagation Delay Time,	$C_L = 15\text{ }\rho F$		150	ns
	Low-To-High-Level Output	$R_L = 3.9\text{ k}\Omega$			
$t_{PHL}$	Propagation Delay Time,	$C_L = 15\text{ }\rho F$		50	ns
	High -To- Low -Level Output	$R_L = 390\text{ k}\Omega$			
$t_{TLH}$	Transition Time,	$C_L = 15\text{ }\rho F$		175	ns
	Low-To-High-Level Output	$R_L = 3.9\text{ k}\Omega$			
$t_{THL}$	Transition Time,	$C_L = 15\text{ }\rho F$		20	ns
	High -To- Low -Level Output	$R_L = 390\text{ k}\Omega$			

**Parameter Measurement Information**

**DRIVER**



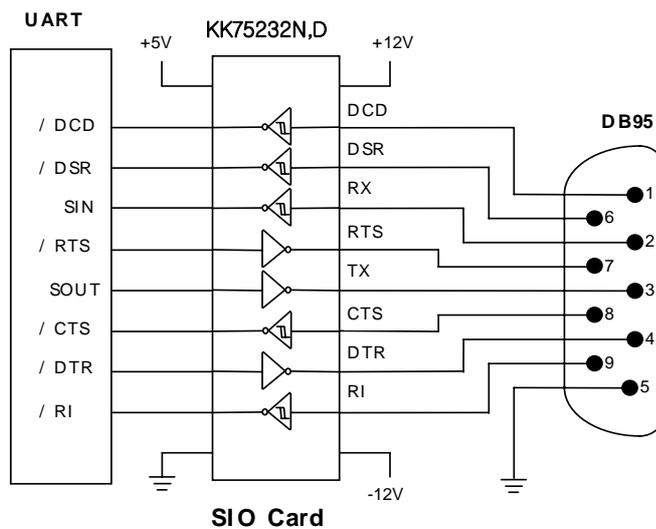
**RESEIVER**



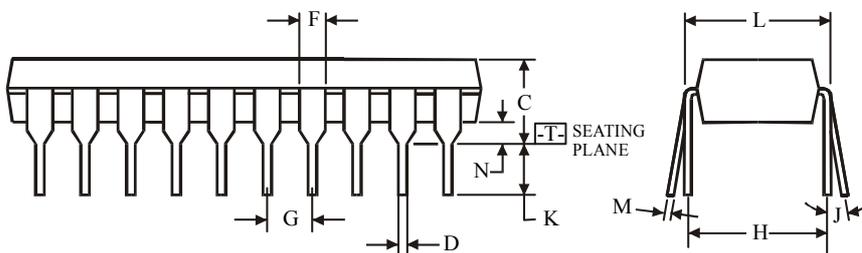
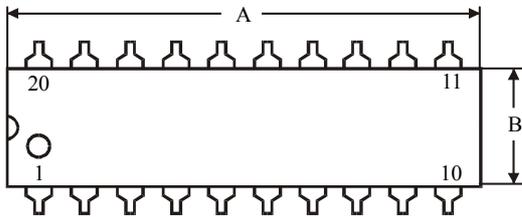
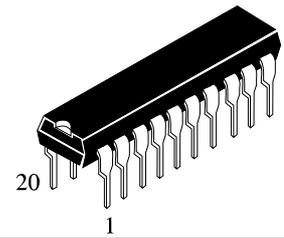
- Note
- A. The pulse generator has the following characteristics.  $f = 200 \text{ KHz}$ ,  $Z_o = 50 \Omega$
  - B. C included probe and jig capacitance.
  - C. All diodes are 1N3064 or equivalent.

Fig1. Propagation and Transition Times

**Typical Application**



**N SUFFIX PLASTIC DIP  
(MS - 001AD)**



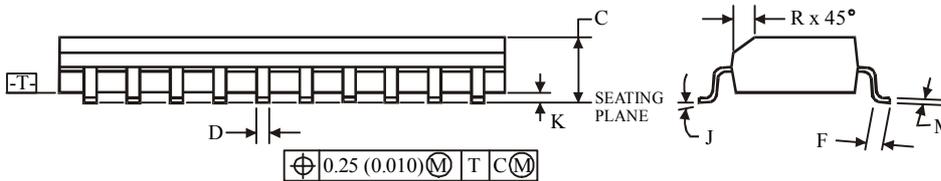
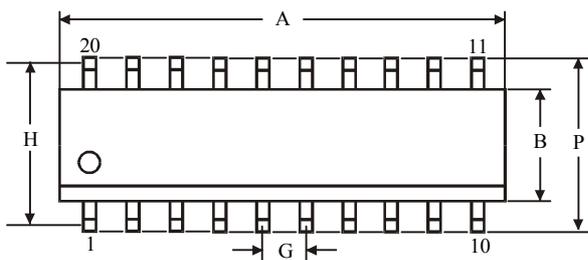
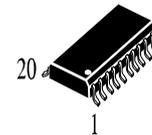
$\oplus 0.25 (0.010) \text{M} \text{T}$

**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions.  
Maximum mold flash or protrusions 0.25 mm (0.010) per side.

Symbol	Dimension, mm	
	MIN	MAX
A	24.89	26.92
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**D SUFFIX SOIC  
(MS - 013AC)**



$\oplus 0.25 (0.010) \text{M} \text{T} \text{C} \text{M}$

**NOTES:**

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.

Symbol	Dimension, mm	
	MIN	MAX
A	12.6	13
B	7.4	7.6
C	2.35	2.65
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	9.53	
J	0°	8°
K	0.1	0.3
M	0.23	0.32
P	10	10.65
R	0.25	0.75